EAST Search History

EAST Search History (Prior Art)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	299	(438/621,319).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/11/22 19:54
L2	2	("20020068430").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/11/22 19:55
L3	2	("5666000").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/11/22 19:55
L4	2	("20030234423").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	WOFF	2009/11/22 19:55
L5	2	("5296408").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	WOFF	2009/11/22 19:56
S1	2	"US 20070170538"	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2009/03/26 14:22
S2	14	((CHRI STOPHE) near2 (REGNI ER)). I NV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/26 14:24
S3	1	((AURELIE) near2 (HUMBERT)).INV.	US-PGPUB; USPAT; USOCR	OR	ON	2009/03/26 14:24
S4	448732	"257"/\$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/26 14:24

S5	2611	257/532.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/26 14:24
S6	759	257/499.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/03/26 14:25
S7	2	"5296408".pn.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2009/03/26 14:30
S8	8578	vacuum same ((integrated adj2 circuit) or (micro adj2 electronic) or semiconductor) same (fabricat\$3)	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2009/03/26 14:32
S9	20	S8 and (S5 or S6)	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2009/03/26 14:33
S10	8	(("20020068430") or ("5,666,000") or ("20030234423") or ("5,296,408")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/08/16 22:39
S11	1	10/589275	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 22:39
S12	46	("4870029" "5011793" "5112436" "5203731"). PN. OR ("5296408"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/16 22:52
S13	4479	mim near3 capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:00
S14	1392	S13 and "438"/\$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:00

S15	101	S14 and (electrode with (void air gap))	US-PGPUB; USPAT; USOCR;	OR	ON	2009/08/16 23:10
			FPRS; EPO; JPO; DERWENT; IBM_TDB			
S16	889	("bottom electrode" "lower electrode") same (dielectric with (air void gap))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:14
S17	556	S16 and capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:15
S18	342	capacitor and (si silicon) with (al aluminum) with (absorb\$4 absorption)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:25
S19	48	S18 and (dielectric with (air void gap))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:26
S20	4157	capacitor and (si silicon) with sacrificial	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:31
S21	10	S18 and S20	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:32
S22	6	("20040100677" "4572615" "5949571" "6034807" "6282010"). PN. OR ("7187487"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/08/16 23:33
S23	4581	(si silicon) with (al aluminum) with (absorb \$4 absorption)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:35

S24	14885	(si silicon) with sacrificial	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:35
S25	34	S23 and S24	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/08/16 23:35
S26	6		US-PGPUB; USPAT; USOCR	OR	ON	2009/08/16 23:37

EAST Search History (Interference)

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11/22/09 7:57:30 PM

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